

isc N-Channel MOSFET Transistor

IPI65R310CFD

• FEATURES

- Static drain-source on-resistance: R_{DS}(on) ≤0.31Ω
- Enhancement mode
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

 Provide all benefits of a fast switching SJ MOSFET while offering an extremely fast and robust body diode

g(1) s(3) pin 1, Gate 2, Drain 3, Source TO-262 package

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	650	V	
V _{GS}	Gate-Source Voltage	±20	V	
I _D	Drain Current-Continuous	11.4	А	
Ірм	Drain Current-Single Pulsed	34.4	А	
P _D	Total Dissipation @T _C =25℃	104.2	W	
Tj	Max. Operating Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature	-55~150	°C	

• THERMAL CHARACTERISTICS

isc website: www.iscsemi.cn

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.2	°C/W	

D	17 00			
		n	nm	1
	DIM	MIN	MAX	1
	A	4.37	4.77	Ť
	A1	1.22	1.42	1
	A2	2.47	2.87	1
	Ъ	0.70	0.97	1
	Ъ2	1.17	1.42	1
	С	0.28	0.53	1
	D	23.20	24.02	1
	D1	8.38	8.90	1
	D2	6.00	-8	1
	Е	9.90	10.39	
	E4	7.30	-	
	е		4BSC	
	G	1.25	1.50	1
	H2	- XI 	1.31	
	L	13.34	14.10	
	L1	3.30	4.06	



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID =1mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID =0.4mA	3.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; ID=4.4A			0.31	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =20V; V _{DS} =0V			0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} =650V; V _{GS} = 0V			1	μА
V _{SD}	Diode forward voltage	I _F =6.6A; V _{GS} = 0V		0.9		V

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